# NSN 5961-01-304-5442

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## Inclosure Material:

Metal

**Overall Length:** 

0.975 inches

# **Overall Height:**

0.210 inches

**Overall Width:** 

0.650 inches

# **Mounting Facility Quantity:**

2

Internal Configuration:

Junction contact

### **Mounting Method:**

Slot

#### Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

60.0 collector to base voltage/static/emitter open and 60.0 collector to emitter voltage, dc with base short-circuited to emitter and 32.0 collector to emitter voltage/static/base open and 3.5 emitter to base voltage, static, collector open

### **Current Rating Per Characteristic:**

3.00 amperes source cutoff current and 750.00 milliamperes source cutoff current

### **Power Rating Per Characteristic:**

32.0 watts small-signal input power, common-collector preset

### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

### **Precious Material And Location:**

Leads and flange plated gold

### Test Data Document:

31550-515538 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

### **Terminal Type And Quantity:**

4 ribbon

Shelf Life:

N/a

### Unit Of Measure:

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## Demilitarization:

Yes - demil/mli

### Fiig:

A110a0